

Remarks:

This preliminary amendment is being submitted in an effort to correct a typographical error in claim 8. No new matter has been added. The changes are not made for any reason related
5 to the statutory requirements for a patent nor do they narrow the scope of the claim for any reason related to the statutory requirements for a patent.

An early action on the merits of the application is solicited.

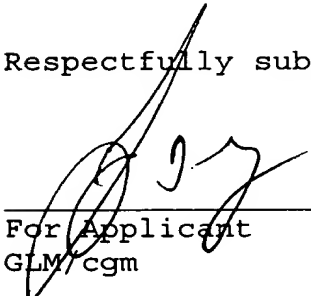
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Please charge any fees that might be due with respect to Sections 1.16 and 1.17 to the Deposit Account of Lerner and Greenberg, P.A., No. 12-1099.

15 Respectfully submitted,

Gregory L. Mayback
Reg. No. 40,719

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For Applicant
GLM/cgm

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Lerner and Greenberg, P.A.
P.O. Box 2480
Hollywood, Florida 33022-2480
Tel.: (954) 925-1100
Fax: (954) 925-1101

Marked-up Version of Claims to Show Changes Made:

Claim 8 (amended). The method according to claim [5]7, which further comprises choosing the magnitude of the doping of the further buffer layer such that, in an operating state in which
5 the semiconductor component effects blocking in the direction from the drain contact toward the source contact, at least in an envisaged range of applied electrical voltages, a space charge zone present in the first base region is formed in a manner extending at least as far as the further buffer layer.